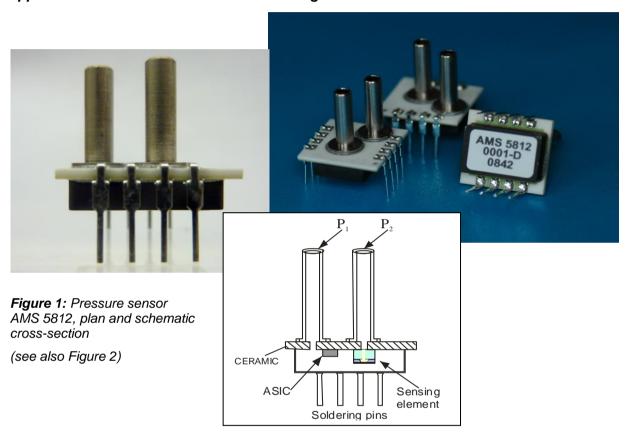


In pressure sensor technology there is a difference between various physical methods of measurement, depending on the application. These include the measurement of absolute pressure, relative pressure, and differential pressure. Many users are not aware of the fact that two different things are understood by "differential pressure measurement". Taking the piezoresistive sensor AMS 5812 [1] as an example, the two versions relevant to practical application shall be illustrated in the following.



To elucidate further, the various methods of pressure measurement and important terms relevant to silicon pressure sensing elements shall be described herein.

#### Measuring absolute pressure

When measuring absolute pressure (see *Figure 2*) pressure  $P_1$  is recorded in relation to a referential pressure of  $P_2$ , which must be so low as to be negligible compared to the pressure  $P_1$ . In an ideal setup, this would be 0bar ( $P_2$  would be the perfect vacuum). This means the sensing element has to place in a vacuum chamber and then hermetically sealed with the Pyrex (glass) substrate in a suitable vacuum of  $P_2$ . This low pressure of  $P_2$  should permanently retain the same value for stability reason.

When pressure  $P_1$  is applied to the upper surface of the membrane, this deforms towards the lower pressure. As  $P_1 >> P_2$  applies, the membrane thus curves inwards into the etched area of the sensing element (see *Figures 2* and *3*). The piezoresistive effect causes a signal to be generated at the output of the implanted Wheatstone resistance bridge (*Figure 4*). This signal is proportional to the

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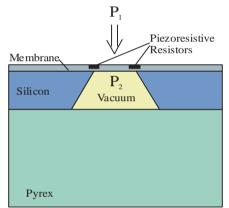


applied pressure  $(V_{OUT} = f(P_1, P_2))$ , but offset and endpoint (full scale signal) are yet to be determined.

As in the production of absolute pressure sensors it is not possible to achieve a referential pressure of 0bar, the actual value of  $P_2$  must serve as a pressure offset. This is brought about by setting the value of  $P_2$  to the required output offset of e.g. 0.5 V, during calibration. This procedure is known as offset calibration.

At full pressure P<sub>1</sub> maximum a full-scale signal is issued at the output which in the signal conditioning electronics is calibrated to the required output value of 4.5 V, for instance.

One popular application involves the measurement of barometric pressure between 700 and 1,200mbar absolute, for example. In this case the offset is calibrated to 700mbar and the full-scale signal to 1,200mbar.



**Figure 2:** Piezoresistive sensing element to determine absolute pressure  $P_1$  with implanted resistors in a Wheatstone bridge

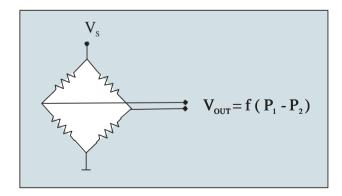
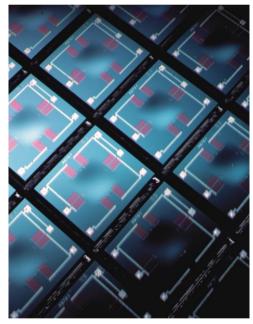


Figure 4: Wheatstone bridge



**Figure 3:** Silicon pressure sensing element for the measurement of absolute pressure (plan)

Light lines = aluminum conducting paths

Light squares = aluminum bond pads

Purple areas = implanted contact areas, with the piezoresistive hidden resistors between them

Area of the silicon pressure sensing element =  $2 \times 2 \text{ mm}^2$ 

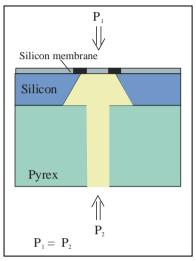
Height of the silicon pressure sensing element = 0.8 mm

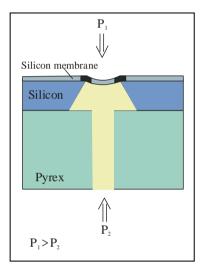
contact: info@amsys-sensor.com



### Measuring differential pressure

When measuring differential pressure, the two pressures  $P_1$  and  $P_2$  are compared which are applied externally through the relevant housing to the upper and lower side of the sensing element. The following applies:  $P_1 \le P_2$  or vice versa  $P_1 \ge P_2$ . With most sensors the requirement is that just one pressure ratio, i.e.  $P_1/P_2 \ge 1$  or  $P_1/P_2 \le 1$  can be recorded and evaluated. In general, measuring pressure with this restriction is called "differential pressure sensing".



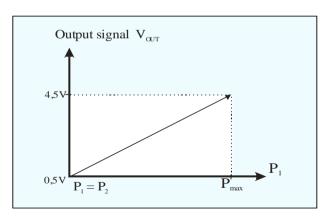


The left graphic in Figure 5 makes the situation  $P_1 = P_2$  clear. The membrane is not deformed and the sensor generates no signal with the same pressure on both sides. But if there is a signal so it is the zero offset voltage which should be calibrated.

If  $P_1 > P_2$  (right), when pressure is applied the membrane deflects towards the lower pressure area; in its piezoresistive bridge it produces an output signal proportional to the pressure of  $V_{OUT} = f(P_1-P_2)$ .

**Figure 5:** How the membrane of a piezoresistive pressure sensor reacts when measuring differential pressure if  $P_1 \ge P_2$ 

At the output of an amplified sensor such as AMS 5812-D the transfer characteristic shown in *Figure 6* is obtained after calibrating the offset and the fullscale signal.



**Figure 6:** Transfer characteristic of a pressure sensor when measuring differential pressure at  $P_1 \le P_2$ 

In addition to the question of whether  $P_1/P_2 \ge 1$  or  $P_1/P_2 \le 1$  should be recorded, for pressure sensors whose membrane has been optimized to suit the required pressure range the condition also applies that  $P_1 - P_2 \le P_{max}$  or  $P_2 - P_1 \le P_{max}$ , with  $P_{max}$  limited by the given technical conditions e.g. package.

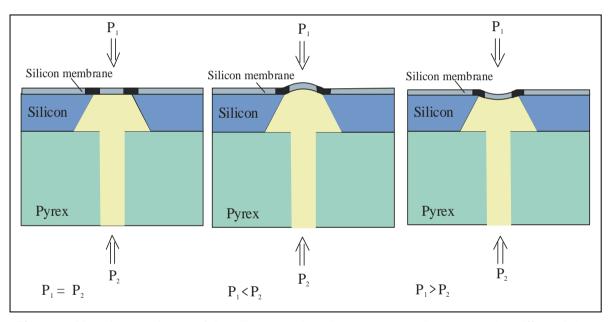
These boundary conditions must be heeded when the user fits pressure connections to the differential sensor and would like to measure differential pressure e.g. in filter control systems.



#### **Bidirectional differential sensors**

Besides the measurement of differential pressure mentioned above there are also applications which require that both conditions  $P_1 \le P_2$  and  $P_1 \ge P_2$  are met in one pressure system. These include, for example, ventilation and air exhaust systems, overshooting and/or undershooting a given liquid level, inhalation and exhalation setups, etc. As there is no generally recognized term for this kind of differential pressure sensing, AMSYS has decided to call sensors that can measure this type of differential pressure "bidirectional differential pressure sensors". These AMSYS sensors e.g. the AMS5812 are thus capable of measuring both negative and positive pressure.

Figure 7 is a schematic diagram of how the deformation of a differential pressure sensing element is to be perceived under the application of negative and positive pressure. The change in polarity in the output signal of the resistor bridge signifies nothing other than a change in the direction of the membrane deformation.



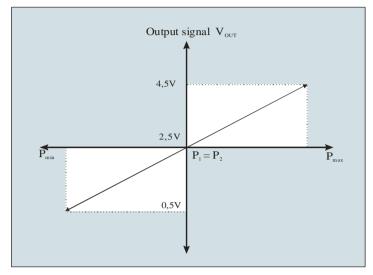
**Figure 7:** How the membrane of the silicon sensing element reacts when measuring differential pressure if  $P_1 = P_2$ ,  $P_1 < P_2$  and  $P_1 > P_2$ 

With the sensing elements of these sensors, the differential pressure to be measured can have both a positive and negative polarity. This means that pressure  $P_1$  at topside of the sensing element can be either greater or smaller than pressure  $P_2$  at on the underside of the sensing element. The polarity can thus vary during measurement. For pressures  $P_1$  and  $P_2$  the following condition applies:

 $P_{min} \leq \left| \ P_1 \text{ - } P_2 \right| \leq P_{max}$  with the boundary condition  $P_1$  ,  $P_2 \leq P_{System}.$ 

In the above formula  $P_{max}$  is the positive and  $P_{min}$  the negative ultimate pressure of the relevant pressure range (see Figure 8) for which the sensors have been designed.  $P_{System}$  is the maximum permissible system pressure, such as ambient pressure, which may be applied externally to the sensor and which is determined by the sensor assembly e.g. package or pressure port.





**Figue 8:** Transfer characteristic for bidirectional differential pressure sensors at  $P_1 = P_2$ ,  $P_1 < P_2$ , and  $P_1 > P_2$ 

Bidirectional differential measurements are only possible when the following two sensor requirements are fulfilled:

the membrane structure must behave symmetrically in that it deflects on both sides, and

the transfer behavior of the signal conditioning electronics must suit the range of amplification in relation to the offset.

Regarding a): the membrane of a piezoresistive sensor is a thin semiconductor layer a few micrometers thick comprising several layerings. As a rule these are the film of silicon, an oxide coating and a passivation layer, with the latter two on the upper surface of the membrane. The layering is thus not symmetrical. Due to this asymmetrical layering the membrane behavior on pressure deflection can be direction dependent. In the worst case, when the direction changes it could be subject to the 'click' effect. This means that with a change in the direction of deflection the membrane demonstrates a discontinuity which is signaled to the user as strong non-linearity, particularly in the range of the offset pressure.

Manufacturers of silicon sensing elements which are to be used for the measurement of bidirectional differential pressure must therefore ensure that the membrane demonstrates a symmetrical behavior with both positive and negative pressure.

Regarding b): the transfer characteristic illustrated in *Figure 8* requires amplifier circuitry in which the instrumentation amplifier is not referenced to zero potential but instead set to half of the full-scale value. For example, in the bidirectional version of AMS 5812, which is to have an output signal of 0.5...4.5 V, the offset is set to 2.5 V so that the signal at  $P_1 \le P_2$  ranges from 0.5 to 2.5 V and at  $P_1 \ge P_2$  from 2.5 to 4.5 V.

#### Measuring relative pressure

Should one of the active pressures  $P_1$  or  $P_2$  be equal to the effective ambient pressure, we then speak of relative pressure sensing, which is a variation on differential pressure measurement. In this case, the difference between measurement pressure  $P_1$  and ambient pressure  $P_2$  is then measured, for example, and  $P_1 \ge P_2$  applies. As here we are measuring against ambient pressure, only one pressure port is required for the measurement pressure.



### **Description of AMS 5812**

One of the AMSYS sensors which is able to measure the differential and the bidirectional differential pressure is the AMS 5812 [1].

The AMS 5812 device described here is an OEM pressure sensor with two parallel outputs: an analog voltage output of 0.5...4.5 V or 2.5 V ±2 V and an I<sup>2</sup>C bus interface.

The output voltage signal is ratiometric to the supply voltage (5 V  $\pm$  5%). The pressure and temperature values can be set using the I<sup>2</sup>C interface. The sensor can be addressed through this interface and given an individual ID.

AMS 5812 devices are individually calibrated during manufacture and compensated for a temperature range of -25 to 85°C. Very accurate measurement, drift stability, and long-term stability are the result of high-quality piezoresistive pressure sensing elements combined with state-of-the-art signal conditioning circuitry in the form of a mixed-signal CMOS-ASIC.

A 15  $\times$  15 mm<sup>2</sup> ceramic substrate with dual inline soldering pins and a ceramic housing give the pressure sensor high mechanical stability.

Different pressure ranges are offered:

AMS 5812: lowest pressure ranges, differential and bidirectional differential:

0-0.075; 0-0.15 PSI / ± 0.075; 0.15 PSI

AMS 5812: low pressure ranges, differential and bidirectional differential:

0-0.3; 0-0.8; 0-1.5 PSI/± 0.3; ±0.8; ±1.5

AMS 5812: standard pressure ranges, differential and bidirectional differential:

0-3; 0-5; 0-15; 0-30; 0-60;  $0-100 PSI/<math>\pm 3$ ;  $\pm 5$ ;  $\pm 15 PSI$ 

AMS 5812: absolute pressure ranges: 0 -5 and 0 -30 PSI and barometric: 11-17.5 PSI

FEATURES	APPLICATIONS
Relative, absolute, differential, and bidirectional differential pressure sensing	Respirators and medical measurement technology in general
Wide pressure range (5mbar to 7bar)	Gas flow and dynamic pressure  magnifecture  121  221  231  241  241  241  241  241
<ul> <li>Analog, ratiometric output voltage</li> </ul>	measurements [2]
• Pressure measurement output through an I <sup>2</sup> C	Heating, ventilation, air conditioning (HVAC)
bus	Barometric measurements
<ul> <li>Temperature output through an I<sup>2</sup>C bus</li> </ul>	Pneumatics
I <sup>2</sup> C bus interface with individual addressing	Vacuum measurement
<ul> <li>High accuracy in a wide operating temperature range</li> </ul>	
Large positive pressure range	
Small package	
No additional components	



### **Summary**

Besides the usual measurement of differential pressure, where a stipulated ratio between higher and lower pressure is measured ( $P_1/P_2 \ge 1$  or  $P_1/P_2 \le 1$ ), there is also a variation known as bidirectional differential pressure sensing which permits both configurations to be measured simultaneously. This particular kind of differential pressure measurement which allows both positive and negative pressure to be measured, is called bidirectional differential pressure measurement and is explained in greater detail in the above, taking AMS 5812 as an example.

#### **Further information**

- [1] Product information AMS 5812: <a href="https://www.amsys-sensor.com/products/pressure-sensor/ams5812-pressure-sensor-with-analog-and-digital-output/">https://www.amsys-sensor.com/products/pressure-sensor-with-analog-and-digital-output/</a>
- [2] Application note on media compatibility AMS 5812: <a href="https://www.amsys-sensor.com/downloads/notes/ams5812-media-compatibility-of-silicon-pressure-sensors-amsys-508e.pdf">https://www.amsys-sensor.com/downloads/notes/ams5812-media-compatibility-of-silicon-pressure-sensors-amsys-508e.pdf</a>

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